74HC2G00-Q100; 74HCT2G00-Q100

Dual 2-input NAND gate Rev. 2 — 20 November 2018

Product data sheet

1. General description

The 74HC2G00-Q100; 74HCT2G00-Q100 is a dual 2-input NAND gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

plastic very thin shrink small outline package;

8 leads; body width 2.3 mm

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - For 74HC2G00-Q100: CMOS level
 - For 74HCT2G00-Q100: TTL level
- Symmetrical output impedance
- High noise immunity •
- Low power dissipation
- Balanced propagation delays
- ESD protection:

-40 °C to +125 °C

MIL-STD-883, method 3015 exceeds 2000 V

VSSOP8

- HBM JESD22-A114F exceeds 2000 V
- MM JESD22-A115-A exceeds 200 V (C = 200 pF; R = 0 Ω)

3. Ordering information

Table 1. Ordering information							
Type number Package							
	Temperature range	Name	Description				
74HC2G00DP-Q100	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package;				
74HCT2G00DP-Q100			8 leads; body width 3 mm; lead length 0.5 mm				

74HC2G00DC-Q100

74HCT2G00DC-Q100



Version SOT505-2

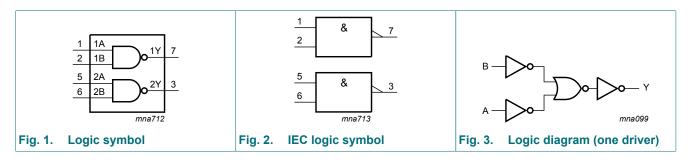
SOT765-1

4. Marking

Type number	Marking code[1]
74HC2G00DP-Q100	H00
74HCT2G00DP-Q100	Т00
74HC2G00DC-Q100	H00
74HCT2G00DC-Q100	Т00

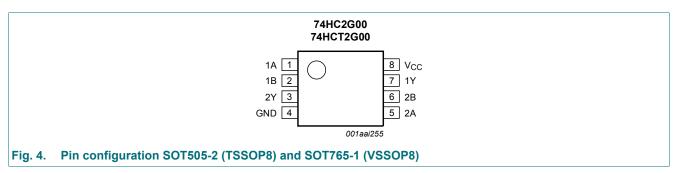
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Symbol	Pin	Description
1A, 2A	1, 5	data input
1B, 2B	2, 6	data input
GND	4	ground (0 V)
1Y, 2Y	7, 3	data output
V _{CC}	8	supply voltage

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output	
nA	nB	nY
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
I _O	output current	$V_{\rm O}$ = -0.5 V to (V _{CC} + 0.5 V)	[1]	-	25	mA
I _{CC}	supply current		[1]	-	50	mA
I _{GND}	ground current		[1]	-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _D	dynamic power dissipation	T_{amb} = -40 °C to +125 °C	[2]	-	300	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.

For VSSOP8 package: above 110 $^\circ\text{C}$ the value of P_{tot} derates linearly with 8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	ditions 74HC2G00-Q100			74HCT2G00-Q100			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
fall rate	fall rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	
74HC2G0	0-Q100							
V _{IH} HIGH-level input		V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I_{O} = -20 µA; V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	V
		I_{O} = -20 µA; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		$I_{O} = -20 \ \mu A; V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	4.13	4.32	-	3.7	-	V
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.63	5.81	-	5.2	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.33	-	0.4	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±1.0	-	±1.0	μA
I _{CC}	supply current	per input pin; $V_I = V_{CC}$ or GND; $I_O = 0 A$; $V_{CC} = 6.0 V$	-	-	10	-	20	μA
CI	input capacitance		-	1.5	-	-	-	pF
74HCT2G	00-Q100	1						-
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	4.13	4.32	-	3.7	-	V
V _{OL}	LOW-level output	V _I = V _{IH} or V _{IL}						
	voltage	I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
I _I	input leakage current	V_{I} = V_{CC} or GND; V_{CC} = 5.5 V	-	-	±1.0	-	±1.0	μA
I _{CC}	supply current	$V_1 = V_{CC}$ or GND; $I_0 = 0$ A; $V_{CC} = 5.5$ V	-	-	10	-	20	μA
ΔI _{CC}	additional supply current	per input; V_{CC} = 4.5 V to 5.5 V; V _I = V _{CC} - 2.1 V; I _O = 0 A	-	-	375	-	410	μA
CI	input capacitance		-	1.5	-	-	-	pF

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); all typical values are measured at T_{amb} = 25 °C; for test circuit see Fig. 6.

Symbol	Parameter	Conditions		-40 °C to +85 °C			-40 °C t	Unit	
			Mir		Тур	Max	Min	Max	1
74HC2G	00-Q100	1	I				-	1	
t _{pd}	propagation delay	nA and nB to nY; see Fig. 5	[1]						
		V _{CC} = 2.0 V		-	25	95	-	110	ns
		V _{CC} = 4.5 V		-	9	19	-	22	ns
		V _{CC} = 6.0 V		-	7	16	-	20	ns
t _t	transition time	see Fig. 5	[2]						
		V _{CC} = 2.0 V		-	18	95	-	125	ns
		V _{CC} = 4.5 V		-	6	19	-	25	ns
		V _{CC} = 6.0 V		-	5	16	-	20	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	[3]	-	10	-	-	-	pF
74HCT20	G00-Q100						1		
t _{pd}	propagation delay	nA and nB to nY; see Fig. 5	[1]						
		V _{CC} = 4.5 V		-	12	24	-	29	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Fig. 5</u>	[2]	-	6	19	-	22	ns
C _{PD}	power dissipation capacitance	V_{I} = GND to V_{CC} - 1.5 V	[3]	-	10	-	-	-	pF

 t_{pd} is the same as t_{PLH} and t_{PHL} . [1]

[2] [3]

 t_t is the same as t_{TLH} and t_{THL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

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11.1. Waveforms and test circuit

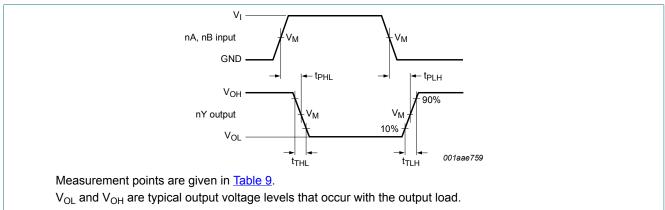
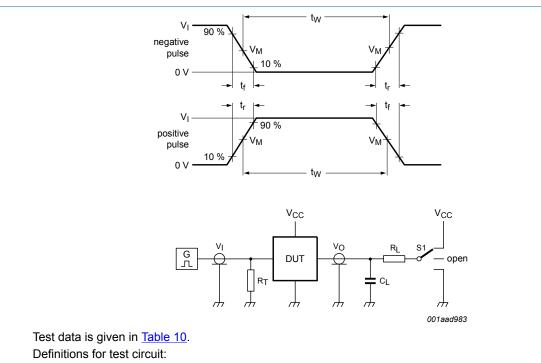


Fig. 5. Propagation delay data input (nA, nB) to data output (nY) and transition time output (nY)

Table 9. Measurement points

Туре	Input	Output	
	V _M	V _M	
74HC2G00-Q100	0.5 x V _{CC}	0.5 x V _{CC}	
74HCT2G00-Q100	1.3 V	1.3 V	



 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator;

 C_L = Load capacitance including jig and probe capacitance; R_L = Load resistance; S1 = Test selection switch.

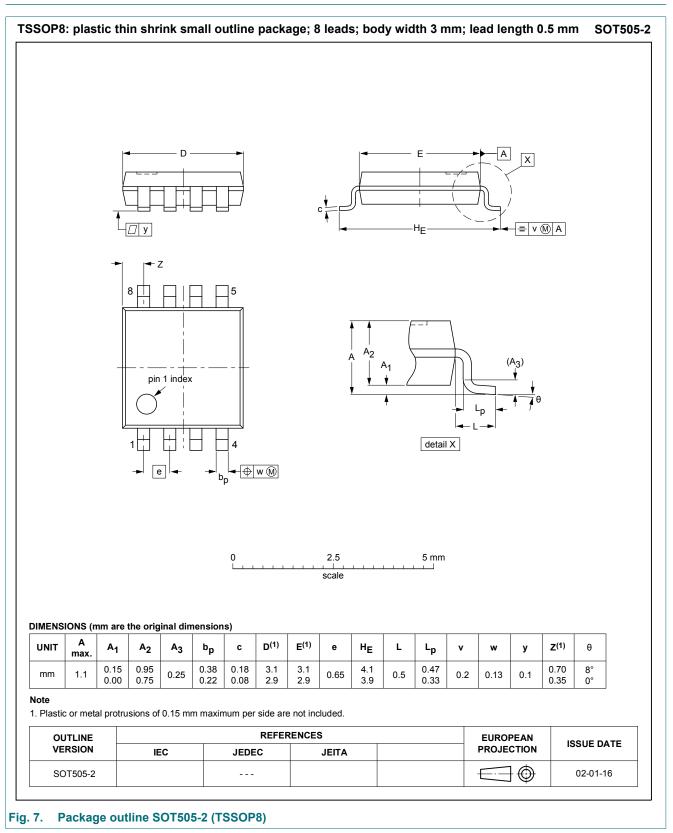
Fig. 6. Test circuit for measuring switching times

Table 10. Test data

Туре	Input		Input Load		Load		S1 position	
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}			
74HC2G00-Q100	V _{CC}	≤ 6 ns	50 pF	1 kΩ	open			
74HCT2G00-Q100	3 V	≤ 6 ns	50 pF	1 kΩ	open			

74HC_HCT2G00_Q100

12. Package outline



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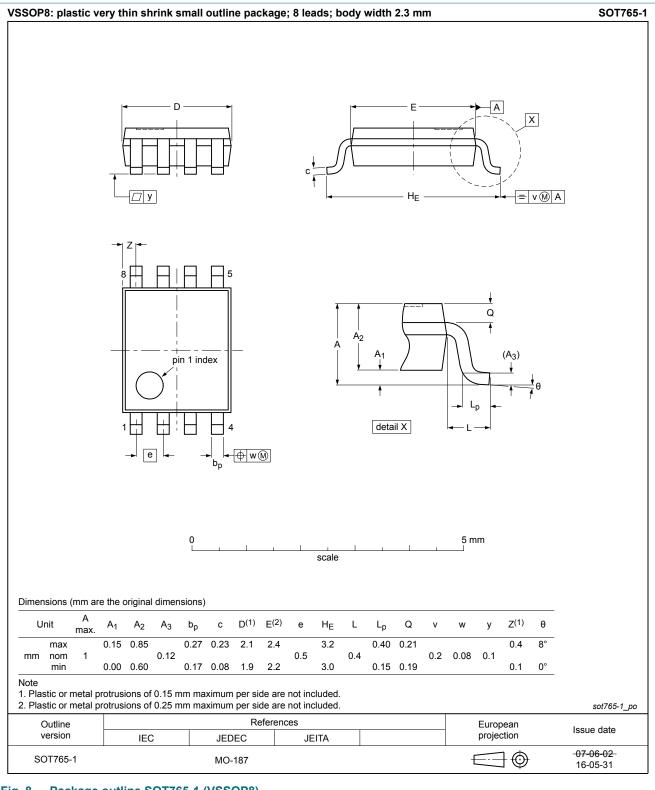


Fig. 8. Package outline SOT765-1 (VSSOP8)

13. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT2G00_Q100 v.2	20181120	Product data sheet	-	74HC_HCT2G00_Q100 v.1		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines Nexperia. Legal texts have been adapted to the new company name where appropriate. 					
74HC_HCT2G00_Q100 v.1	20131107	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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